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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# 3SK317

## Silicon N-Channel Dual Gate MOS FET UHF / VHF RF Amplifier

REJ03G1247-0200

(Previous: ADE-208-778)

Rev.2.00

Aug. 10, 2005

### **Features**

• Low noise characteristics; (NF = 1.0 dB typ. at f = 200 MHz)

• High power gain characteristics; (PG = 27.6 dB typ. at f = 200 MHz)

### **Outline**

RENESAS Package code: PTSP0004ZA-A

(Package name: CMPAK-4)



1. Source 2. Gate1

3. Gate2

Note: Marking is "ZR-".

## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

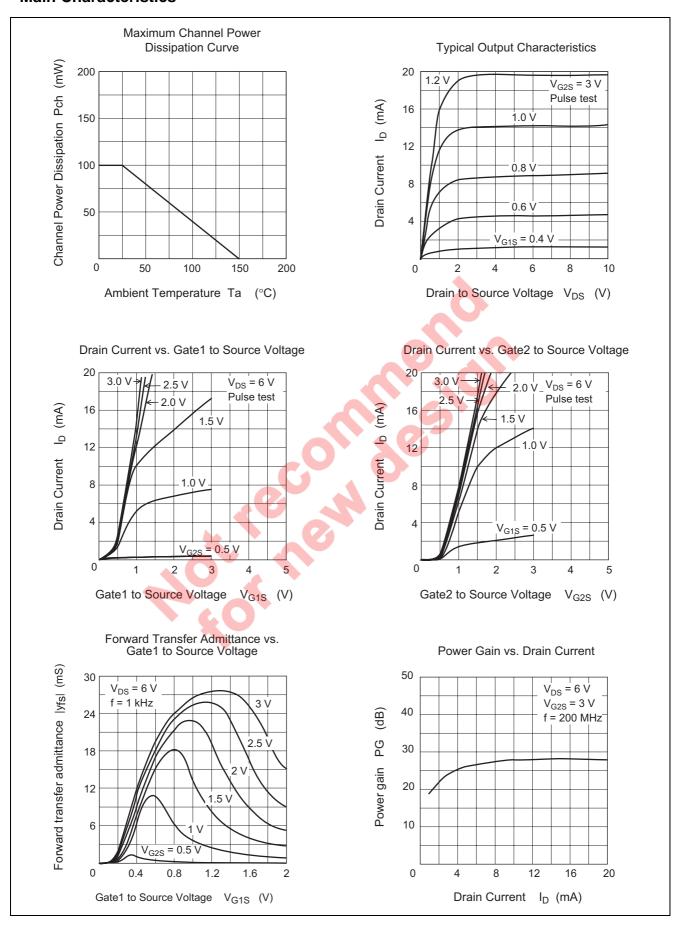
Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DS</sub>	14	V
Gate1 to source voltage	V <sub>G1S</sub>	±8	V
Gate2 to source voltage	V <sub>G2S</sub>	±8	V
Drain current	I <sub>D</sub>	25	mA
Channel power dissipation	Pch	100	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

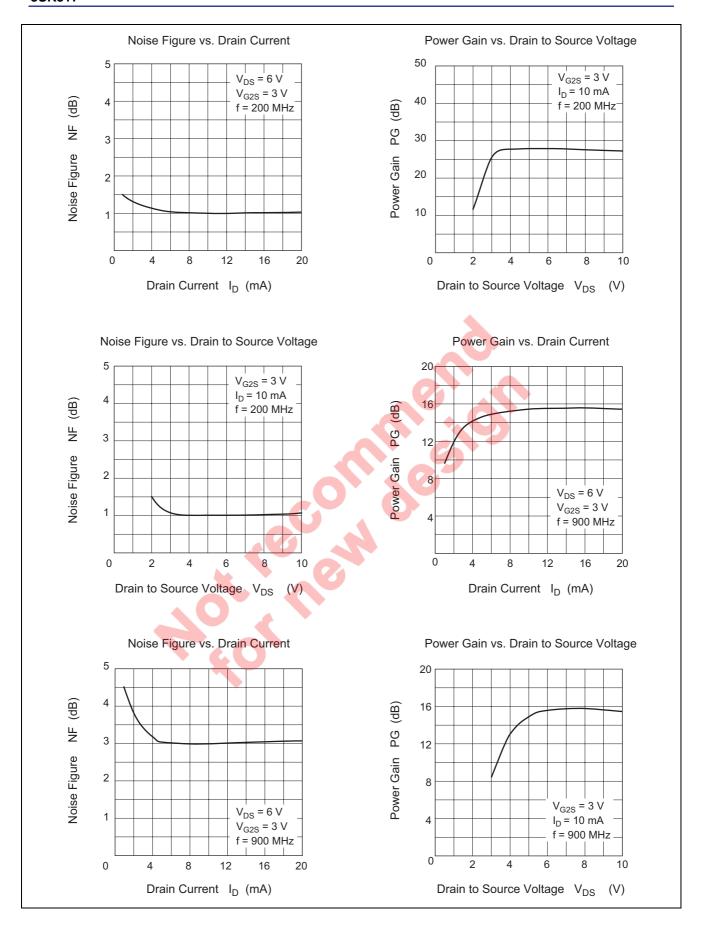
## **Electrical Characteristics**

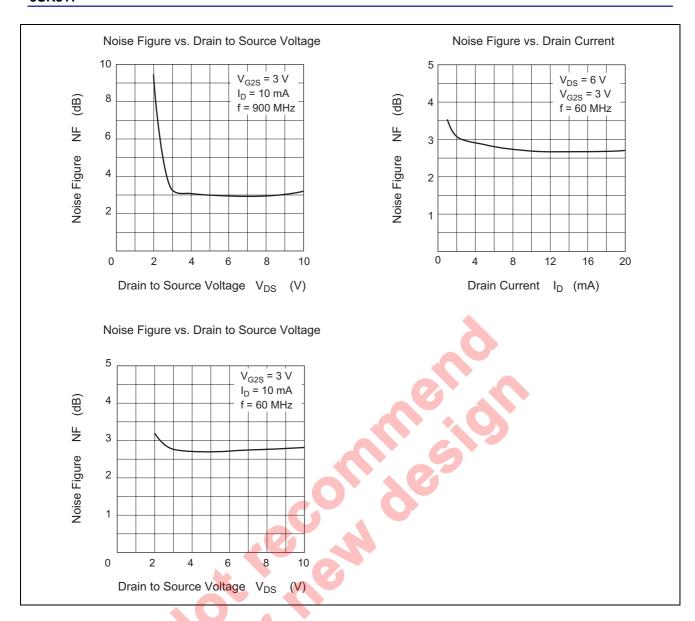
 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	14	_	_	V	$I_D = 200~\mu A$ , $V_{G1S} = V_{G2S} = -3~V$
Gate1 to source breakdown voltage	V <sub>(BR)G1SS</sub>	±8	_	_	V	$I_{G1} = \pm 10 \ \mu A, \ V_{G2S} = V_{DS} = 0$
Gate2 to source breakdown voltage	$V_{(BR)G2SS}$	±8	_	_	V	$I_{G2} = \pm 10 \ \mu A, \ V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff current	I <sub>G1SS</sub>	_		±100	nA	$V_{G1S} = \pm 6 \text{ V}, V_{G2S} = V_{DS} = 0$
Gate2 to source cutoff current	I <sub>G2SS</sub>	_		±100	nΑ	$V_{G2S} = \pm 6 \text{ V}, V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff voltage	V <sub>G1S(off)</sub>	0	0.2	1	V	$V_{DS} = 10 \text{ V}, V_{G2S} = 3 \text{ V},$
						I <sub>D</sub> = 100 μA
Gate2 to source cutoff voltage	$V_{G2S(off)}$	0	0.3	1	V	$V_{DS} = 10 \text{ V}, V_{G1S} = 3 \text{ V},$
						I <sub>D</sub> = 100 μA
Drain current	I <sub>DS(op)</sub>	4	8	14	mA	$V_{DS} = 6 \text{ V}, V_{G1S} = 0.75 \text{ V},$
						$V_{G2S} = 3 V$
Forward transfer admittance	y <sub>fs</sub>	20	25		mS	$V_{DS} = 6 \text{ V}, V_{G2S} = 3 \text{ V}$
						$I_D = 10 \text{ mA}, f = 1 \text{ kHz}$
Input capacitance	Ciss	2.4	3.1	3.5	pF	$V_{DS} = 6 \text{ V}, V_{G2S} = 3 \text{ V},$
Output capacitance	Coss	0.8	1.1	1.4	pF	$I_D = 10 \text{ mA}, f = 1 \text{ MHz}$
Reverse transfer capacitance	Crss	+73	0.021	0.04	pF	
Power gain	PG	24	27.6	_	dB	$V_{DS} = 6 \text{ V}, V_{G2S} = 3 \text{ V},$
Noise figure	NF		1.0	1.5	dB	I <sub>D</sub> = 10 mA , f = 200 MHz
Power gain	PG	12	15.6	_	dB	V <sub>DS</sub> = 6 V, V <sub>G2S</sub> = 3 V,
Noise figure	NF	_	3	4	dB	$I_D = 10 \text{ mA, f} = 900 \text{ MHz}$
Noise figure	NF	_	2.7	3.5	dB	V <sub>DS</sub> = 6 V, V <sub>G2S</sub> = 3 V
<u> </u>						$I_D = 10 \text{ mA}, f = 60 \text{ MHz}$

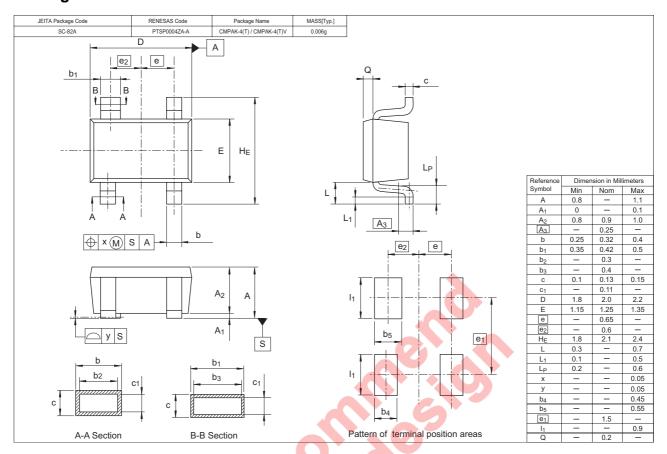
#### **Main Characteristics**







### **Package Dimensions**



## **Ordering Information**

Part Name	Quantity		Shipping Container
3SK317ZR-TL-E	3000	φ17	78 mm Reel, 8 mm Emboss Taping

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Renesas Technology Europe Limited
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Renesas Technology Malaysia Sdn. Bhd.

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